

Positive Temperature Coefficient (PTC) Data Sheet

Description

The 1210 series provides surface mount resettable overcurrent protection with holding current from 0.05A to 2.0A. This series is suitable for wide range of applications in modern electronics where space is limited.



Features

- RoHS compliant and lead-free
- Halogen-free
- Compact design saves board space
- Low profile
- Fast response to fault current
- Compatible with high temperature solders

Applications

- Battery PCM
- USB hubs, ports and peripherals
- Set-top-box and HDMI

- Game console port protection
- Optical disk drives
- General electronics

Agency Approval and Environmental Compliance

Agency	File Number
UL/CUL	E201431
TUV	R50099121

Regulation	Standard
RoHS	2011/65/EU
Halogen Free	IEC 61249-2-21:2003

Electrical Characteristics

Part				Maximum Time To Trip		Resistance		Agency Approval			
Number	(A)	(A)	(Vdc)	(A)	(W)	Current (A)	Time (Sec.)	R _{min} (Ω)	R_{1max} (Ω)	UL /CUL	TUV
SMD1210P005TF	0.05	0.15	30	10	0.60	0.25	1.50	3.600	50.00	$\sqrt{}$	$\sqrt{}$
SMD1210P010TF	0.10	0.30	30	10	0.60	0.50	1.50	1.600	15.00	\checkmark	$\sqrt{}$
SMD1210P020TF	0.20	0.40	30	10	0.60	8.00	0.02	0.800	5.000	\checkmark	$\sqrt{}$
SMD1210P035TF	0.35	0.70	6	100	0.60	8.00	0.20	0.320	1.300	\checkmark	$\sqrt{}$
SMD1210P050TF	0.50	1.00	13.2	100	0.60	8.00	0.05	0.250	0.900	\checkmark	$\sqrt{}$
SMD1210P075TF	0.75	1.50	6	100	0.60	8.00	0.10	0.130	0.400	\checkmark	$\sqrt{}$
SMD1210P075TF/24	0.75	1.50	24	100	0.60	8.00	0.10	0.130	0.400	\checkmark	$\sqrt{}$
SMD1210P110TFT	1.10	2.20	8	100	0.60	8.00	0.10	0.060	0.210	\checkmark	$\sqrt{}$
SMD1210P110TF/12	1.10	2.20	12	100	0.60	8.00	0.10	0.060	0.210	\checkmark	$\sqrt{}$
SMD1210P110TF/16	1.10	2.20	16	100	0.60	8.00	0.10	0.060	0.210	\checkmark	$\sqrt{}$
SMD1210P150TFT	1.50	3.00	6	100	0.80	8.00	0.30	0.040	0.110	\checkmark	$\sqrt{}$
SMD1210P150TF/12	1.50	3.00	12	100	0.80	8.00	0.30	0.040	0.110	\checkmark	$\sqrt{}$
SMD1210P150TF/16	1.50	3.00	16	100	0.80	8.00	0.30	0.040	0.110	V	V
SMD1210P175TF	1.75	3.50	6	100	0.80	8.00	0.60	0.020	0.080	V	V
SMD1210P200TF	2.00	4.00	6	100	0.80	8.00	1.00	0.015	0.070	V	V



Note on Electrical Characteristics

Vocabulary

- I_{hold} = Hold current: maximum current device will pass without tripping in 23℃ still air.
- I_{trip} = Trip current: minimum current at which the device will trip in 23°C still air.
- V_{max} = Maximum voltage device can withstand without damage at rated current (I_{max})
- I_{max} = Maximum fault current device can withstand without damage at rated voltage (V_{max})
- P_{d typ.} = Typical power dissipated from device when in the tripped state at 23℃ still air.
- R_{min} = Minimum resistance of device in initial (un-soldered) state.
- R_{1max} = Maximum resistance of device at 23 ℃ measured one hour after tripping or reflow soldering of 260 ℃ for 20 sec.
- Value specified is determined by using the PWB with 0.030"*1.5oz copper traces.
- Caution: Operation beyond the specified rating may result in damage and possible arcing and flame.
- Specifications are subject to change without notice.

Polymeric PTC Selecting Guide

- Determine the following operating parameters for the circuits:
 - Normal operating current (I_{hold})
- Maximum interrupt current (I_{max})
- Maximum circuit voltage (V_{max})
- Normal operating temperature surrounding device (min °C/max °C)
- Select the device from factor and dimension suitable for the application:
 - Surface Mount Device (SMD)
- Axial Leaded Device (ALD)
- · Other Customized Form Factors

- Radial Leaded Device (RLD)
- DISC Device
- Compare the maximum rating for V_{max} and I_{max} of the PPTC device with the circuit in application and make sure the circuit's requirement does not exceed the device rating.
- Check that PPTC device's trip time (time-to-trip) will protect the circuit.
- Verify that the circuit operating temperature is within the PPTC device's normal operating temperature range.
- Verify that performance and suitability of the chosen PPTC device in the application.

A WARNING

Mechanical Stress

PPTC devices will undergo a thermal expansion during fault condition. If PPTC devices are installed or placed in an application
where the space between PPTC devices and the surrounding materials (e.g., covering materials, packaging materials, encapsulate
materials and the like) is insufficient, it will cause an inhibiting effect upon the thermal expansion. Pressing, twisting, bending and
other kinds of mechanical stress will also adversely affect the performance of the PPTC devices, and shall not be used or applied.

Chemical Pollutants

 Silicone-based oils, oils, solvents, gels, electrolytes, fuels, acids, and the like will adversely affect the properties of PPTC devices, and shall not be used or applied.

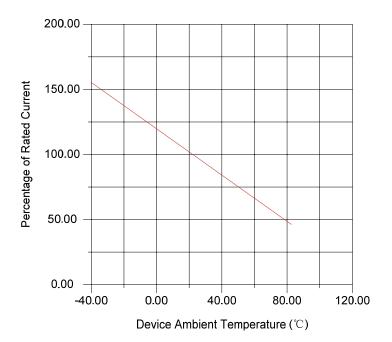
■ Electronic and Thermal Effect

- PPTC devices are secondary protection devices and are used solely for sporadic, accidental over-current or over-temperature error condition, and shall NOT be used if or when constant or repeated fault conditions (such fault conditions may be caused by, among others, incorrect pin-connection of a connector) or over-extensive trip events may occur.
- PPTC devices are different from fuses and, when a fault condition occurs, will go into high-resistance state and do not open circuit, in which case the voltage at such PPTC devices may reach a hazardous level.
- Operation over the maximum rating or other forms of improper use may cause failure, arcing, flame and/or other damage to the PPTC devices.
- Conductive material contamination, such as metal particle, may induce shortage, flame or arcing.
- Due to the inductance, the operation circuits may generate a circuit voltage (Ldi/dt) above the rated voltage of PPTC devices, which shall not be used under such circumstances.

General

- Customers shall evaluate and test the properties of PPTC devices independently to verify and ensure that their individual
 applications will be met.
- The performance of PPTC devices will be adversely affected if they are improperly used under electronic, thermal and/or mechanical procedures and/or conditions non-conformant to those recommended by manufacturer.
- Customers shall be responsible for determining whether it is necessary to have back-up, failsafe and/or fool-proof protection
 To avoid or minimize damage that may result from extra-ordinary, irregular function or failure of PPTC devices.
- · Any and all responsibilities and liabilities are disclaimed if any item under this notice of warning is not complied with.

Thermal Derating Curve

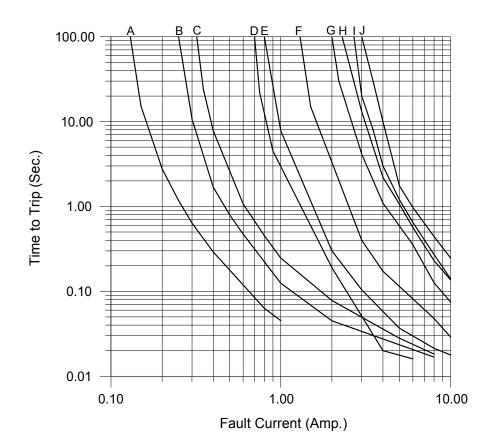


Thermal Derating Chart

Recommended Hold Current (A) at Ambient Temperature ($^{\circ}$ C)

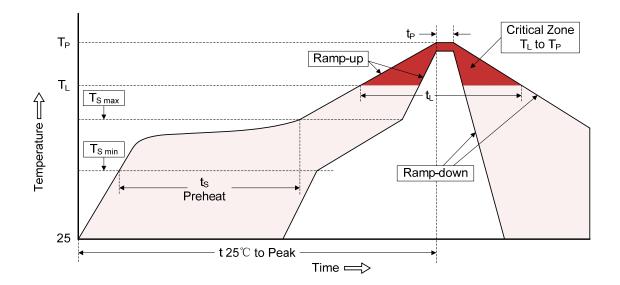
Part	Ambient Operation Temperature								
Number	-40℃	-20℃	0℃	23℃	40℃	50℃	60℃	70℃	85℃
SMD1210P005TF	0.08	0.07	0.06	0.05	0.04	0.04	0.03	0.03	0.02
SMD1210P010TF	0.16	0.14	0.12	0.10	0.08	0.07	0.06	0.05	0.05
SMD1210P020TF	0.29	0.26	0.22	0.20	0.16	0.14	0.13	0.11	0.08
SMD1210P035TF	0.47	0.45	0.40	0.35	0.33	0.28	0.24	0.21	0.18
SMD1210P050TF	0.76	0.67	0.58	0.50	0.43	0.40	0.36	0.32	0.28
SMD1210P075TF	1.00	0.97	0.86	0.75	0.64	0.59	0.54	0.48	0.40
SMD1210P075TF/24	1.00	0.97	0.86	0.75	0.64	0.59	0.54	0.48	0.40
SMD1210P110TFT	1.60	1.42	1.26	1.10	0.94	0.86	0.80	0.70	0.58
SMD1210P110TF/12	1.60	1.42	1.26	1.10	0.94	0.86	0.80	0.70	0.58
SMD1210P110TF/16	1.60	1.42	1.26	1.10	0.94	0.86	0.80	0.70	0.58
SMD1210P150TFT	2.30	2.02	1.76	1.50	1.24	1.11	1.00	0.85	0.65
SMD1210P150TF/12	2.30	2.02	1.76	1.50	1.24	1.11	1.00	0.85	0.65
SMD1210P150TF/16	2.30	2.02	1.76	1.50	1.24	1.11	1.00	0.85	0.65
SMD1210P175TF	2.45	2.22	2.01	1.75	1.45	1.26	1.10	0.98	0.80
SMD1210P200TF	2.60	2.44	2.35	2.00	1.78	1.67	1.50	1.45	1.10

Average Time-Current Curve



- A SMD1210P005TF
- B SMD1210P010TF
- C SMD1210P020TF
- D SMD1210P035TF
- E SMD1210P050TF
- F SMD1210P075TF SMD1210P075TF/24
- G SMD1210P110TFT SMD1210P110TF/12 SMD1210P110TF/16
- H SMD1210P150TFT SMD1210P150TF/12 SMD1210P150TF/16
- I SMD1210P175TF
- J SMD1210P200TF

Soldering Parameters



Profile Feature	Pb-Free Assembly
Average ramp-up rate (T _{S max} to T _P)	3°C/second max.
Preheat -Temperature Min (T_{Smin}) -Temperature Max (T_{Smax}) -Time (min to max) $(T_{Smin}$ to $T_{Smax})$	150℃ 200℃ 60-180 seconds
Time maintained above: -Temperature (T_L) -Time (t_L)	217℃ 60-150 seconds
Peak Temperature (T _P)	260℃
Time within 5°C of actual Peak Temperature (t _P)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25℃ to Peak Temperature	8 minutes max.
Storage Condition	0°C~35°C, ≤70%RH

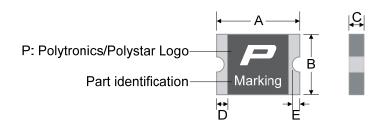
- Recommended reflow methods: IR, vapor phase oven, hot air oven, N2 environment for lead-free
- Recommended maximum paste thickness is 0.25mm (0.010 inch)
- Device can be cleaned using standard industry methods and solvents.

Note 1: All temperature refer to topside of the package, measured on the package body surface.

Note 2: If reflow temperatures exceed the recommended profile, devices may not meet the performance requirements.



Physical Dimensions (mm)



Part	, ,	Ą	E	3	()	[)	ŀ	≣
Number	Min.	Max.								
SMD1210P005TF	3.0	3.43	2.35	2.80	0.75	1.25	0.25	0.75	0.10	0.50
SMD1210P010TF	3.0	3.43	2.35	2.80	0.75	1.25	0.25	0.75	0.10	0.50
SMD1210P020TF	3.0	3.43	2.35	2.80	0.60	1.00	0.25	0.75	0.10	0.50
SMD1210P035TF	3.0	3.43	2.35	2.80	0.50	0.85	0.25	0.75	0.10	0.50
SMD1210P050TF	3.0	3.43	2.35	2.80	0.50	0.85	0.25	0.75	0.10	0.50
SMD1210P075TF	3.0	3.43	2.35	2.80	0.50	0.85	0.25	0.75	0.10	0.50
SMD1210P075TF/24	3.0	3.43	2.35	2.80	1.20	1.80	0.25	0.75	0.10	0.50
SMD1210P110TFT	3.0	3.43	2.35	2.80	0.30	0.71	0.25	0.75	0.10	0.50
SMD1210P110TF/12	3.0	3.43	2.35	2.80	0.75	1.25	0.25	0.75	0.10	0.50
SMD1210P110TF/16	3.0	3.43	2.35	2.80	0.75	1.25	0.25	0.75	0.10	0.50
SMD1210P150TFT	3.0	3.43	2.35	2.80	0.75	1.07	0.25	0.75	0.10	0.50
SMD1210P150TF/12	3.0	3.43	2.35	2.80	0.75	1.25	0.25	0.75	0.10	0.50
SMD1210P150TF/16	3.0	3.43	2.35	2.80	0.75	1.25	0.25	0.75	0.10	0.50
SMD1210P175TF	3.0	3.43	2.35	2.80	0.60	1.00	0.25	0.75	0.10	0.50
SMD1210P200TF	3.0	3.43	2.35	2.80	0.80	1.60	0.25	0.75	0.10	0.50

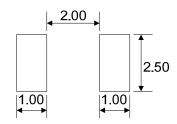
Environmental Specifications

Operating / Storage temperature	-40°C to +85°C
Maximum Device Surface Temperature in Tripped State	125℃
Passive Aging	+85℃, 1000 hours ±5% typical resistance change
Humidity Aging	+85℃, 85%R.H. 1000 hours ±5% typical resistance change
Thermal Shock	MIL-STD-202, Method 107G +85℃/-40℃ 20 times -30% typical resistance change
Solvent Resistance	MIL-STD-202, Method 215 No change
Vibration	MIL-STD-883C, Method 2007.1, Condition A No change
Moisture Level Sensitivity	Level 1, J-STD-020C



Packaging Quantity and Marking

Recommended Pad Layout (mm)



Part Number	Marking	Quantity
SMD1210P005TF	005	3000
SMD1210P010TF	010	3000
SMD1210P020TF	02	3000
SMD1210P035TF	03	4000
SMD1210P050TF	05	4000
SMD1210P075TF	07	4000
SMD1210P075TF/24	075	2000
SMD1210P110TFT	10	4000
SMD1210P110TF/12	12	3000
SMD1210P110TF/16	16	3000
SMD1210P150TFT	15	3000
SMD1210P150TF/12	52	3000
SMD1210P150TF/16	56	3000
SMD1210P175TF	17	3000
SMD1210P200TF	20	2000

^{© 8}mm tape on 7 inch reel per EIA-481 (equivalent to IEC286, part 3)

Physical Specifications

Terminal Material	Solder-Plated Copper (Solder Material: Matte Tin (Sn))
Lead Solderability	Meets EIA Specification RS186-9E, ANSI/J-STD-002 Category 3.



Packaging

Таре		Dimensions (mm)					
	Symbol	P035TF P050TF P075TF P110TF	P005TF, P010TF P020TF, P175TF P150TFT P110TF/12 P110TF/16 P150TF/12 P150TF/16	P200TF	P075TF/24		
P_1	W	8.00±0.30	8.00±0.30	8.00±0.30	8.00+0.30/-0.10		
\rightarrow $P_0 \leftarrow$ $P_0 \leftarrow$	F	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05		
	E ₁	1.75±0.10	1.75±0.10	1.75±0.10	1.75±0.10		
	D_0	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05		
	D ₁	1.00(MIN)	1.00(MIN)	1.00(MIN)	1.00+0.25/-0		
	P ₀	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10		
$-T$ D_1	P ₁	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10		
κ ₀	P ₂	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05		
	A ₀	2.82±0.10	2.82±0.10	2.80±0.10	2.80±0.10		
	B ₀	3.46±0.10	3.50±0.10	3.50±0.10	3.55±0.10		
	Т	0.25±0.10	0.20±0.10	0.25±0.10	0.25±0.10		
	K ₀	1.00±0.10	1.30±0.10	1.60±0.10	1.75±0.10		
	Leader min.	390	390	390	390		
	Trailer min.	160	160	160	160		
Reel H.	С	Ф178.0±1.0					
Dc	D	Ф60.2±0.5					
	Н		11.0-	±0.5			
↓ ⊢W	W	9.0±1.5					

Part Number System

